

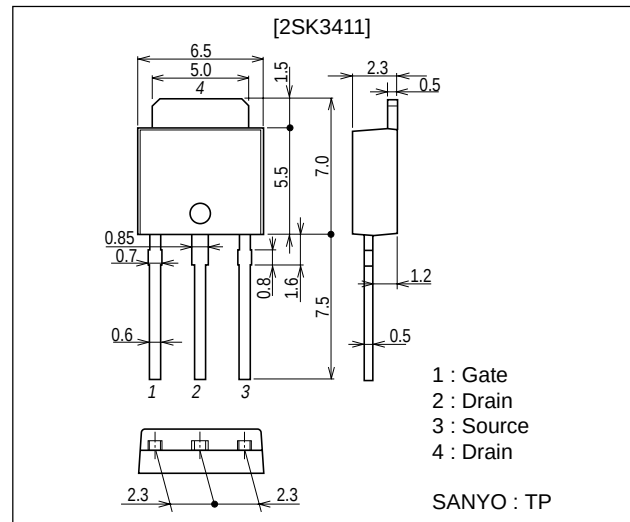
**2SK3411****DC / DC Converter Applications****Features**

- Low ON-resistance.
- Ultrahigh-speed switching.
- 4V drive.

Package Dimensions

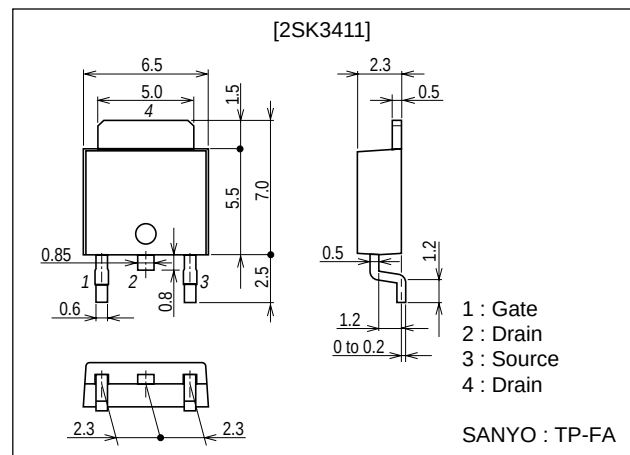
unit : mm

2083B



unit : mm

2092B



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Specifications

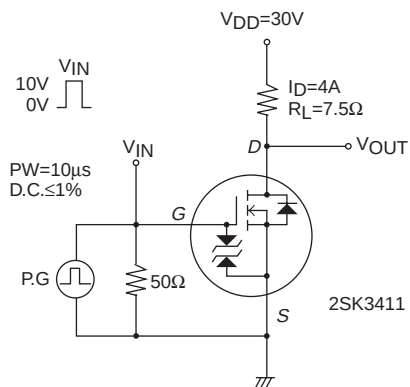
Absolute Maximum Ratings at Ta=25°C

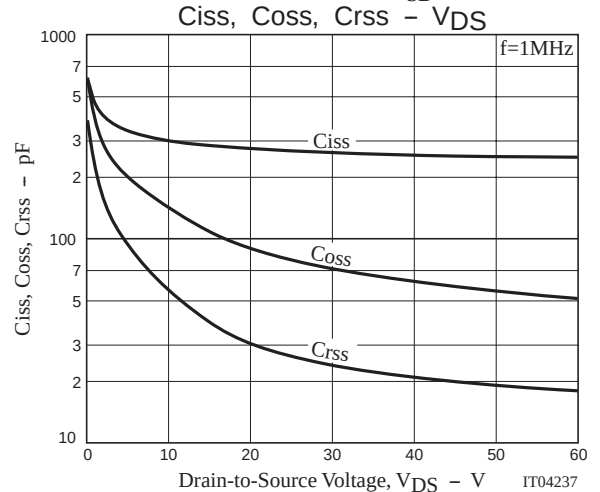
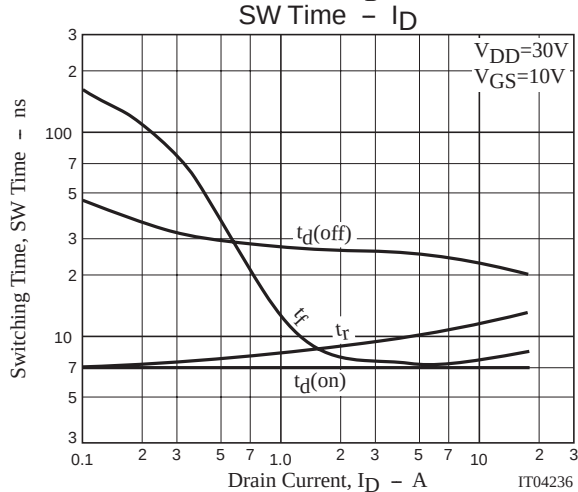
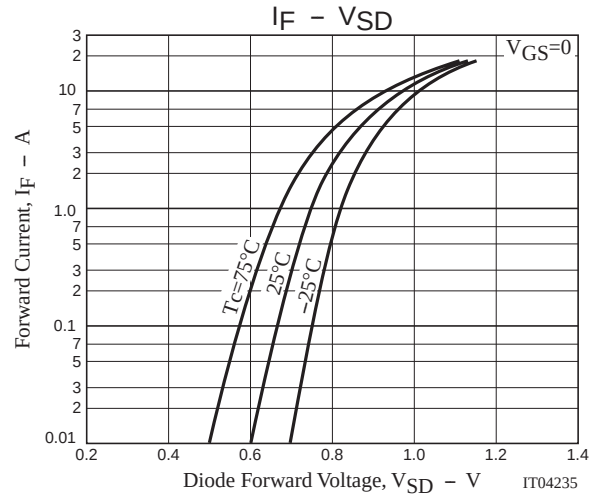
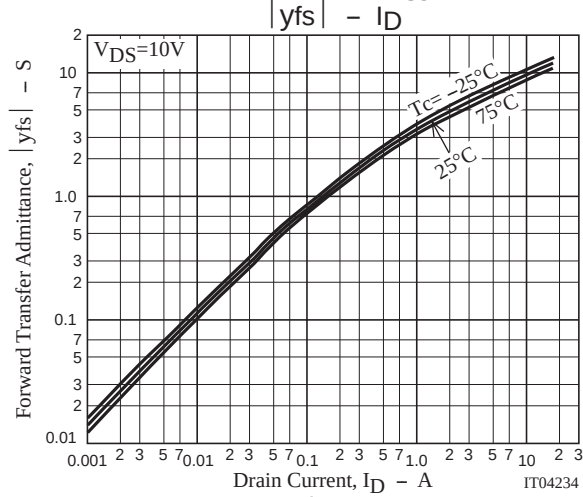
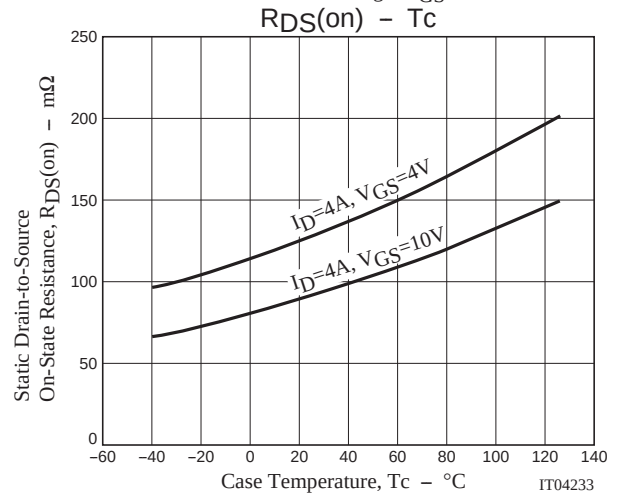
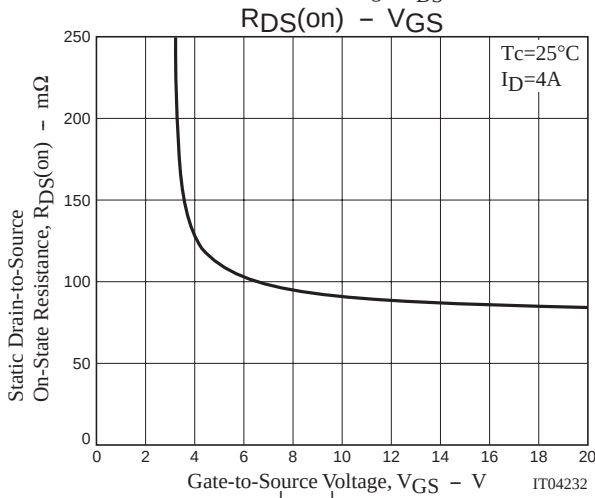
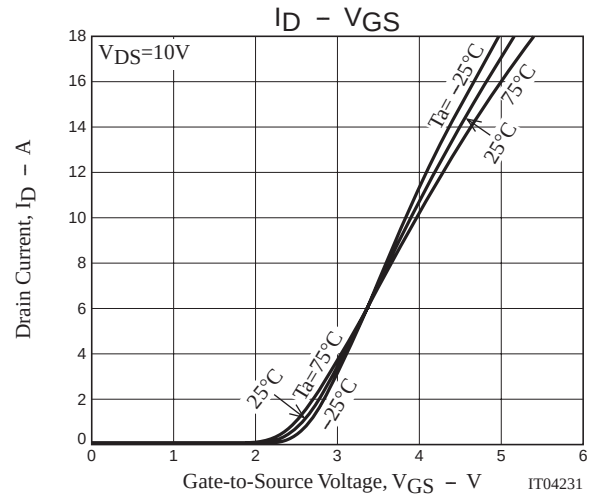
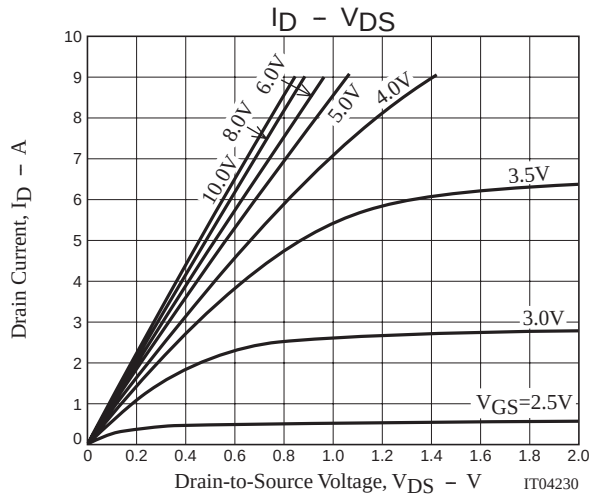
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		60	V
Gate-to-Source Voltage	V_{GSS}		±20	V
Drain Current (DC)	I_D		9	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	36	A
Allowable Power Dissipation	P_D		1	W
		$T_c = 25^\circ C$	15	W
Channel Temperature	T_{ch}		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

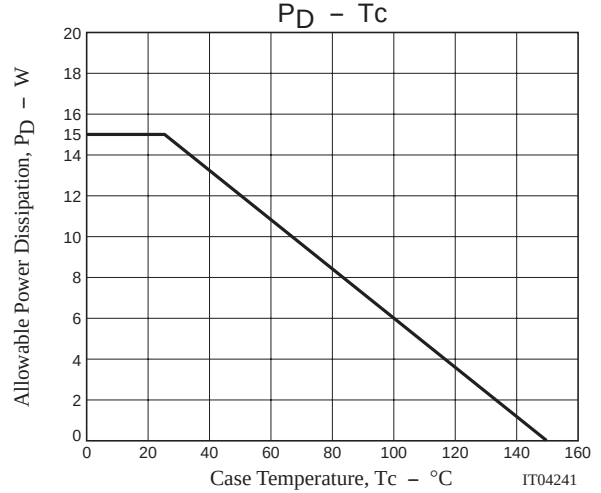
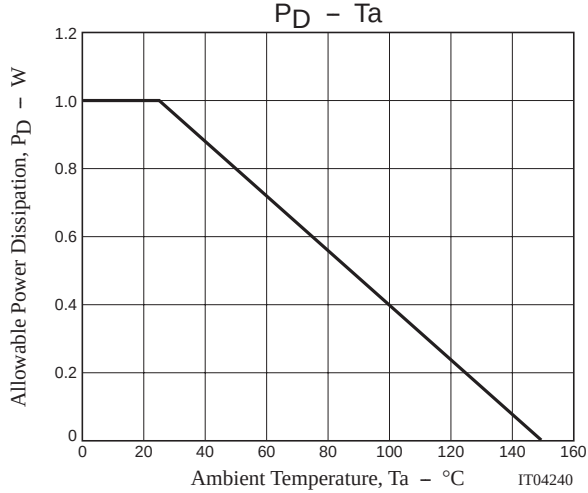
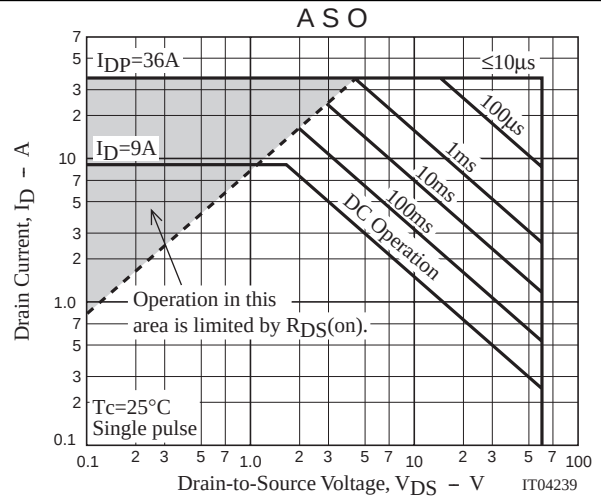
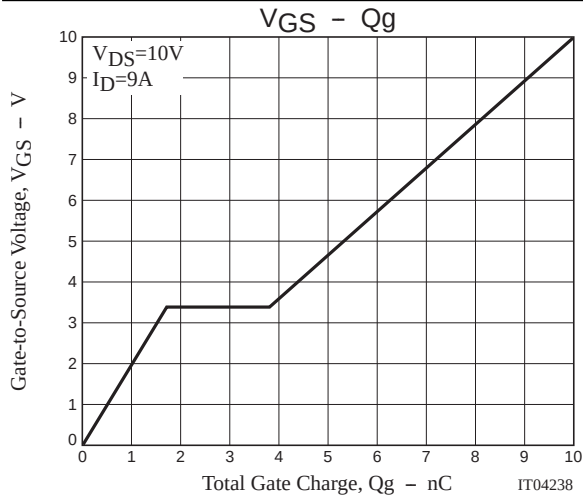
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 1mA$, $V_{GS} = 0$	60			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 60V$, $V_{GS} = 0$			10	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 16V$, $V_{DS} = 0$			±10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = 10V$, $I_D = 1mA$	1.0		2.4	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = 10V$, $I_D = 4A$	4.5	6.5		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D = 4A$, $V_{GS} = 10V$		94	122	mΩ
	$R_{DS(on)2}$	$I_D = 4A$, $V_{GS} = 4V$		125	175	mΩ
Input Capacitance	C_{iss}	$V_{DS} = 20V$, $f = 1MHz$		280		pF
Output Capacitance	C_{oss}	$V_{DS} = 20V$, $f = 1MHz$		90		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS} = 20V$, $f = 1MHz$		30		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		7		ns
Rise Time	t_r	See specified Test Circuit.		10		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit.		26		ns
Fall Time	t_f	See specified Test Circuit.		8		ns
Total Gate Charge	Q_g	$V_{DS} = 10V$, $V_{GS} = 10V$, $I_D = 9A$		10		nC
Gate-to-Source Charge	Q_{gs}	$V_{DS} = 10V$, $V_{GS} = 10V$, $I_D = 9A$		1.7		nC
Gate-to-Drain "Miller" Charge	Q_{gd}	$V_{DS} = 10V$, $V_{GS} = 10V$, $I_D = 9A$		2.1		nC
Diode Forward Voltage	V_{SD}	$I_S = 9A$, $V_{GS} = 0$		0.95	1.2	V

Switching Time Test Circuit







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